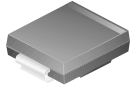


RoHS Compliant Product

A suffix of "-C" specifies halogen-free



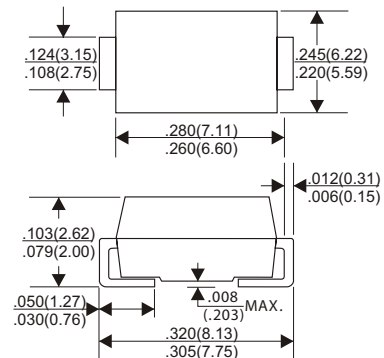
DO-214AB(SMC)

## FEATURES

- \* Ideal for surface mount applications
- \* Easy pick and place
- \* Built-in strain relief
- \* Super Fast switching speed under 35ns

## MECHANICAL DATA

- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Metallurgically bonded construction
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any
- \* Weight: 1.10 grams



Dimensions in inches and (millimeters)

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.  
Single phase half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

TYPE NUMBER	SUF501C	SUF502C	SUF503C	SUF504C	SUF505C	UNITS	
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	V	
Maximum RMS Voltage	35	70	140	280	420	V	
Maximum DC Blocking Voltage	50	100	200	400	600	V	
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at Ta=55°C						5.0	A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)						120	A
Maximum Instantaneous Forward Voltage at 5.0A	0.98			1.25	1.7	V	
Maximum DC Reverse Current Ta=25°C						5.0	µA
at Rated DC Blocking Voltage Ta=100°C						80	µA
Maximum Reverse Recovery Time (Note 1)						35	nS
Typical Junction Capacitance (Note 2)						50	pF
Operating and Storage Temperature Range T <sub>J</sub> , T <sub>STG</sub>						-65~ +175	°C

NOTES:

1. Reverse Recovery Time test condition: I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>RR</sub>=0.25A
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

RATING AND CHARACTERISTIC CURVES (SUF501C THRU SUF505C)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

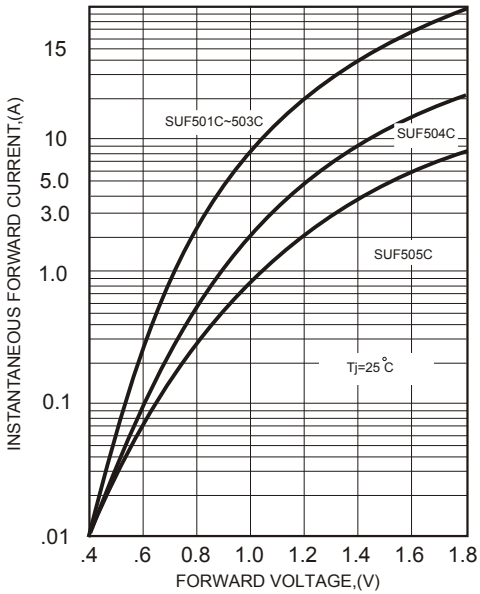


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

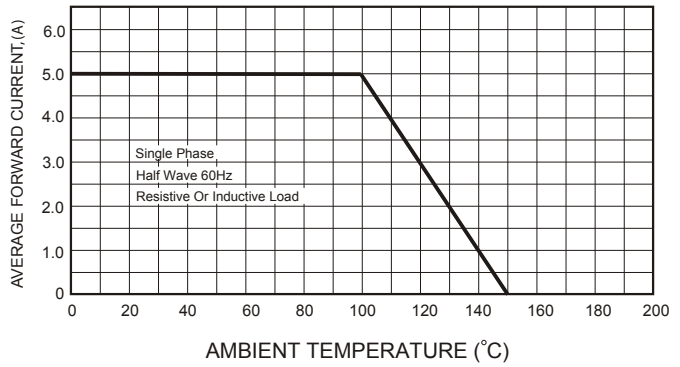


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

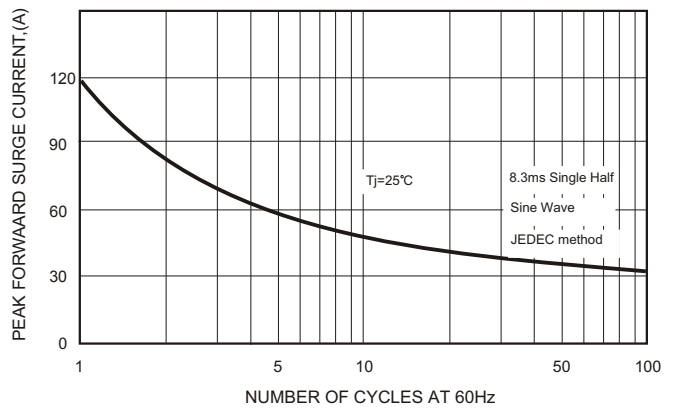
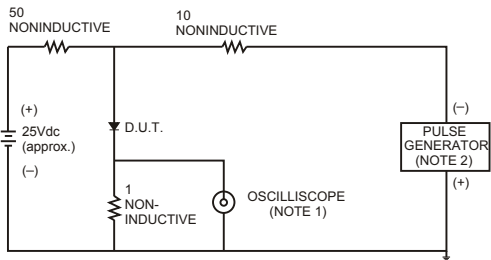


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm.22pF.  
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

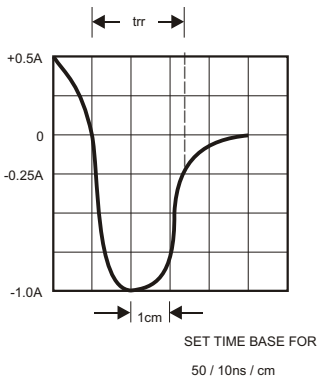


FIG.5-TYPICAL JUNCTION CAPACITANCE

